

* Discuss the different band of semi-conductor? with energy gap.

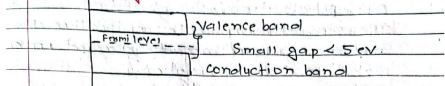


Fig: Energy band of Semiconductors.

1) Valence band
In electrical insulators and semiconductors, the valence band is the highest range of electron energies in which electrons are normally present at absolute zero temperature. For example, a silicon atom has four valence electrons.

In the ground state they are arranged in the electronic configuration $1s^2 2s^2 2p^6 3s^2 3p^2$. Of these four are valence electrons, occupying the 3s orbital and two of the 3p orbitals.

2) Conduction band
The conduction band is the lowest range of free electron states in electrical insulators and semiconductors.

On a graph of the electronic band structure of material the valence band is located below the Fermi level, while the conduction band above it.

3) Energy gap
The band gap in semiconductors is very low must be approximately 1 eV.
The semiconductors act as insulators at very low temperatures and that gradually begins conducting as the temperature increases.

Explain N-type and P-type Semiconductors?

Ans: N-type Semiconductors
If pentavalent impurity such as phosphorous (P) is added to pure Semiconductors Silicon (Si) N-type Semiconductors obtained.

The fifth electron has no chance of forming of covalent bond this electron is loosely bound to the parent atom and free.

Each impurity atom donated one free electron to conduction band.

Due to region pentavalent impurities are also called donor type impurities.

In N-type Semiconductors electron are majority carriers and hole are minority carriers.

Ans: P-type Semiconductors
If trivalent impurity such as boron (B) is added to pure germanium (Ge) crystal P-type Semiconductors is obtained.

With four surrounding germanium atom one bond is left in complete and give rise to hole.

In this case three valence electron of boron atom form covalent bond.

Therefore each carbon atom added one hole is created.

A small amount of carbon provide million of hole. Boron atom accept one electron to complete covalent bond.

Due to region trivalent impurities are also called acceptor impurity.

In this type hole are majority carriers & electrons are minority carriers.

Explain iron alloys?

a) Ferritic, iron chromium alloy.
These alloys consist of mainly iron, chromium (90-95%) and aluminium (4-5%).

low cost heating element.
High resistivity good thermal conductivity.
used in toaster and other small appliances.

b) Iron-nickel-chromium alloys.
These are basically two group of alloys: Ni-Cr-Fe alloys with excellent strength at high temperature and the ability to resist oxidation, carburisation and other types of high-temperature corrosion.

c) Ferritic chromium-aluminium alloy.
used as heating element in hot plate iron electric furnaces.
used in heavy duty switches and resistor application.
Excellent life time, domestic appliances, heater etc.

Uses of Nickel?

i) Aircraft gas turbines.
ii) medical application.
iii) nuclear power plant.
iv) chemical and petrochemical industries.
v) make coins.
vi) making wires.

making various types of alloys.

Explain dielectric material?

The materials which do not conduct electricity are called dielectric material.
e.g. glass, plastic, mica, nitrogen, dry air, hydrogen, transformer oil, silicon fluids, etc.

Explain dielectric constant?
The ratio of relative permittivity and permittivity of free space of a substance is called dielectric constant.

Explain dielectric breakdown?
Electric or dielectric breakdown is a long reduction in the resistance of an insulator when the voltage applied across it exceeds the breakdown voltage. This result in the insulator becoming electrically conductive.

Difference between dielectric breakdown & strength.

Dielectric breakdown is the failure of an insulating material to prevent the flow of current.	Dielectric strength is the voltage than an insulating material can withstand before breakdown occurs.
The value of electrical potential at which this occurs is called breakdown voltage (measured in volt).	The dielectric strength is the potential gradient while this occurs (expressed in volt per meter).
breakdown voltage will be large for thicker material and smaller for thinner material.	Dielectric strength remain unchanged.

Explain dielectric breakdown in solid, gas and liquid?

Ans: Dielectric breakdown in solid.

- Thermal breakdown.
- Electro-mechanical breakdown.
- conductive breakdown.
- Intrinsic breakdown.

Thermal breakdown:

In heterogeneous dielectric the presence of nonuniform (varying) electric resistance across dielectric could cause uneven leakage current flow through it.

In that region when the current intense the resulting would raise the temperature lowering the electrical resistivity. This effect result in thermal breakdown by electric conduction.

Electromechanical breakdown:

This refers to mechanical failure in a dielectric due to intense electrostatic pressure exerted on dielectric.

Conductive breakdown:

It is caused by ionic charge carriers in the dielectric that move in it at electric field itself produced additional ion collision of electrons and molecules so that current increase with increase in voltage.

Intrinsic breakdown:

When voltage are applied only for short duration of order of 10^{-8} second, the dielectric strength of solid increases very to an upper limit is called intrinsic breakdown of material.

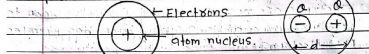
What is polarization? Explain electronic and ionic polarization?

Ans: Polarization.

The separation of center of positive charged and the center of negative charged in a material called polarization.

Ans: Electronic polarization:

Electronic polarization occurs due to the displacement of the centre of negatively charged electron relative to positive charge of atoms by electric field.



No applied field (E=0) applied field (E≠0)

Fig: Electronic polarization.

Example of electronic polarization are helium and argon etc. The shifting electron cloud result in dipole moments and it is defined as the product of and shifting distance.

The dipole moment 'p' is directly proportional to the electric field E.

i.e. $p \propto E$

where ϵ_0 is constant of proportionality and called coefficient of electronic polarization.

The polarization is independent upon temperature.

Electronic polarization can be calculate by:

$\epsilon_e = \frac{p}{E}$

where ϵ_e = electronic polarization, p = dipole moment, E = electric field.

Atomic number, m_e = mass of electron.

ω = oscillation frequency of centre of mass of electron.

What are insulating material? and it's characteristic?

Ans: Insulating material.

A materials that responds with very high resistance to the flow of electric current is called an insulating material.

In insulating materials the valence electrons are tightly bonded to their atoms.

e.g. plastic, porcelain, glass, mica, oil, gases (SF₆).

Ans: Characteristics of insulating materials.

- Large insulating resistance.
- Small dielectric loss.
- low permittivity.
- High dielectric strength, mechanical strength & high thermal strength.
- Very low electrical and thermal conductivity.

Uses of insulating materials?

- high voltage appliances.
- circuit boards.
- power and electronics system.
- cable and transmission lines.
- Electrical safety mats.
- personal protective equipment.
- domestic portable appliances.

Properties of insulating gases?

- high dielectric strength, high thermal stability.
- low toxicity and low boiling point.
- good heat transfer properties.
- low cost.
- Non-flammability.
- good dielectric properties.

Explain domain structure and eddy current loss?

Ans: Domain structure.

A magnetic domains is a region within a magnetic material which have uniform magnetization.

This means that the individual magnetic moments of the atoms are aligned with one another and they point in the same direction.

These magnetic domains are responsible for magnetic behaviour of ferromagnetic material.

The region separating the magnetic domain are called domain structure domain wall.

Ans: Eddy current loss.

When an alternating magnetic field is applied to the magnetic material the material is subjected to rate of change of flux linkage according to Faraday's law of electromagnetic induction an emf are induced in the material. Some current will circulate in the core and this circulating current is known as eddy current.

This results in the heating up of the material which cause the loss of energy called eddy current loss.

In order to reduce eddy current loss in practical application, the core can be made thin sheets laminated which are electrically insulated each other.

Eddy current loss is depend on the nature of materials.

Explain ferroelectricity and piezoelectricity?

Ans: Ferroelectricity.

Certain crystal like barium titanate (BaTiO₃) which have large permanent polarization even in the absence of electric field are ferroelectricity crystal and this phenomenon is called ferroelectricity.

example of ferroelectricity materials are BaTiO₃ & PZT etc.

Ans: properties of ferroelectricity.

- Extremely high dielectric constant.
- spontaneous polarization in the absence applied electric field.
- Strong non-linear dielectric response to an applied electric field.
- high strain response to applied electric field.
- strong variation in polarization with temperature.

Ans: piezoelectricity.

piezoelectricity is the electric charged that accumulates in certain solid material in response to applied mechanical stress.

The word piezo electricity means electricity resulting from pressure.

Ans: properties of piezo electricity.

- high strain (charge) constants, permittivity.
- low mechanical quality factor.
- high curie temperature range and thermal stability.
- high strain output useful for large displacement at modest voltage.
- The d₃₃ values are also estimated by the stress induced charge based on direct piezoelectric effect.

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